



#### Radiation-Hard Optical Link for SLHC

W. Fernando, K.K. Gan, A. Law, H.P. Kagan, R.D. Kass, S. Smith The Ohio State University

> M.R.M. Lebbai, P.L. Skubic University of Oklahoma

> > July 20, 2007

HEP2007







- Introduction
- Bandwidth of micro twisted-pair cables
- Bandwidth of fusion spliced SIMM-GRIN fiber
- Radiation hardness of PIN/VCSEL arrays
- Results on MT-style optical packages based on BeO
- Summary



upgrade based on current pixel link architecture
 to take advantage of R&D effort and production experience?
 K.K. Gan HEP2007 3



## **R&D** Issues for SLHC



- bandwidth of ~ 1 Gb/s is needed
  - can micro twisted pair transmit at this speed?
  - can fusion spliced SIMM/GRIN fiber transmit at this speed?
- can PIN/VCSEL arrays survive SLHC radiation dosage?







• current pixel cable with thick insulation is quite optimum! K.K. Gan HEP2007 5







127 μm cable 140 cm 100 μm current pixel cable 140 cm 60 cm



• transmission at 1280 Mb/s may be acceptable

• 127 μm cable is slightly better K.K. Gan



#### 1 m GRIN fiber



#### • transmission up to 2 Gb/s looks adequate

HEP2007

8 + 80 m spliced SIMM/GRIN fiber







- Optical link of current pixel detector is mounted on patch panel:
  - much reduced radiation level:
    - Si (PIN) @ SLHC:
      - 2.5 x  $10^{15}$  1-MeV  $n_{eq}/cm^2$
      - $4.3 \times 10^{15} \text{ p/cm}^2 \text{ or } 114 \text{ Mrad for } 24 \text{ GeV protons}$
    - GaAs (VCSEL) @ SLHC:
      - 14 x 10<sup>15</sup> 1-MeV  $n_{eq}/cm^2$
      - 2.7 x 10<sup>15</sup> p/cm<sup>2</sup> or 71 Mrad for 24 GeV protons
    - above estimates include 50% safety margin



# Requirements for PIN/VCSE

- PIN:
  - What is responsivity after irradiation?
  - What is rise/fall time after irradiation?
- VCSEL:
  - driver chip most likely be fabricated with 0.13 µm process
    - nominal operating voltage is 1.2 V
    - thick oxide option can operate at 2.5 V
    - ➡ VCSELs must need < 2.3 V to produce 10 mA or more</p>
  - What is rise/fall time after irradiation?
  - What is optical power after irradiation?
  - What current is needed for annealing?



### **PIN Responsivity**





#### • responsivity decreases by 65% after SLHC dosage

HEP2007





0.0

### VCSEL Power vs Dosage







more VCSELs might survive with more annealing during irradiation K.K. Gan







- current pixel detector uses Taiwan optical packages
  - OVER WORK OF CONTROL OF CONTRO
  - micro soldering of 250 μm leads is difficult
- Ohio State develops new opto-pack for SLHC
  - uses BeO base with 3D traces for efficient heat removal
  - wire bond to driver/receiver chip



IEP2007





### Results on Opto-Packs

• 30 VCSEL/PIN opto-packs have been fabricated

- all VCSEL opto-packs have good coupled power
- ⇒ principle of new opto-pack has been demonstrated





### Summary



- micro twisted-pair cable of current ATLAS pixel detector can be used for transmission up to 1 Gb/s
- fusion spliced SIMM/GRIN fiber can transmit up to 2 Gb/s
- PIN responsivity decreases by 65% after SLHC dosage
- Optowell VCSEL survives SLHC dosage
- ➡ current opto-link architecture satisfies SLHC requirements
- compact MT-style opto-pack based on BeO has been developed